

N-Channel Silicon MOSFET

# ECH8402 — General-Purpose Switching Device Applications

### Features

- · Low ON-resistance.
- 4V drive.

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱D		10	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	40	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0		2.4	V
Forward Transfer Admittance	yfs	VDS=10V, ID=5A	5.6	9.4		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	ID=5A, VGS=10V		11	15	mΩ
	R <sub>DS</sub> (on)2	ID=2.5A, VGS=4V		23	32	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		1400		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		270		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		190		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		17		ns
Rise Time	tr	See specified Test Circuit.		82		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		96		ns
Fall Time	tf	See specified Test Circuit.		53		ns

Marking : KB

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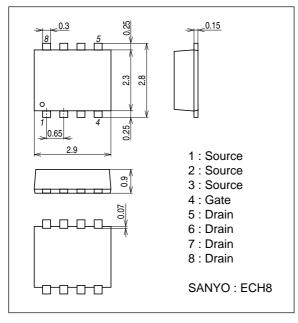
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#### Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Total Gate Charge	Qg	VDS=10V, VGS=10V, ID=5A		28		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =5A		4.8		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=10V, VGS=10V, ID=5A		7.3		nC
Diode Forward Voltage	VSD	IS=10A, VGS=0		0.81	1.2	V

#### **Package Dimensions**

unit : mm 2222A

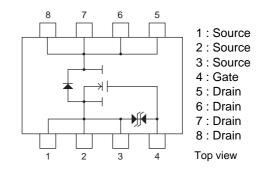


#### **Switching Time Test Circuit**

#### V<sub>DD</sub>=15V VIN 10V 10V ID=5A VIN $R_L=3\Omega$ D ⊸ Vout PW=10µs D.C.≤1% G À , ECH8402 $\gtrless 50\Omega$ P.G (\_\_\_\_\_ .s $\pi$ ID - VDS ID - VGS 16 10 V<sub>DS</sub>=10V 40.4 8.01 6.01 14 È 8 5V 2 12 Drain Current, ID - A Drain Current, ID - A 10 6 8 4 6 $V_{GS}=3.0V$ 4 2 3 0 0 1.0 1.5 2.0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 0.5 2.5 3.0 3.5 4.0 0 0 Drain-to-Source Voltage, V<sub>DS</sub> - V Gate-to-Source Voltage, $V_{GS} - V$

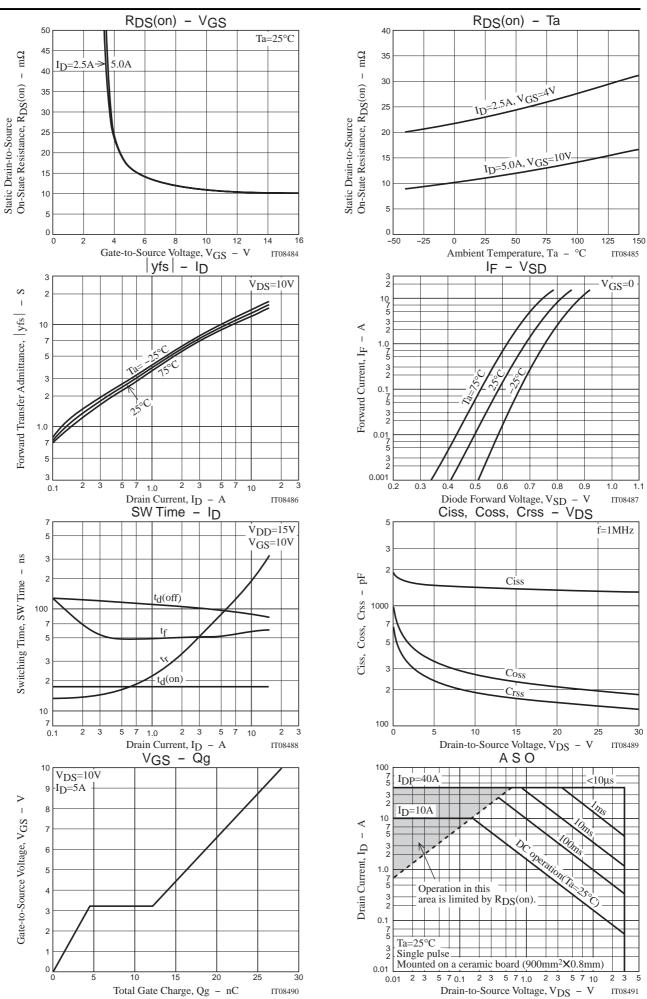
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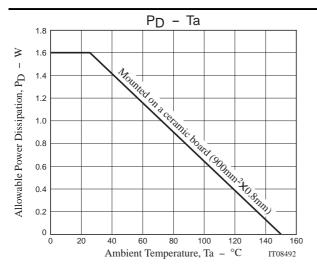
### **Electrical Connection**



4.5 5.0

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# Note on usage : Since the ECH8402 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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